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CONTENTS

Crystal growth from boiling solutions 1
R. RODRIGUEZ-CLEMENTE, S. VEINTEMILLAS-VERDAGUER, F. RULL-PÉREZ and K. SANGWAL

Silicon ingot casting by gas assisted solidification 41
C. H. CHU, C. Y. SUN and H. L. HWANG

Crystal growth of gallium nitride 53
D. ELWELL and M. M. ELWELL

Diamond and diamond-like films: deposition from the vapour phase, structure and properties 79
B. V. SPITSYN, L. L. BOUILOV and B. V. DERJAGUIN

Low cost, non-vacuum techniques for the preparation of thin/thick films for photovoltaic applications 171
S. OKTIK

The growth and characterisation of ZnSe epilayers grown by VPE and MOCVD 241
YAN-KUIN SU, CHUNG-CHENG CHANG and CHUNG-CHUANG WEI

Solidification behaviour of organic nonlinear optical crystals 265
N. B. SINGH, M. E. GLICKSMAN and R. MAZELSKY

Phase equilibria and crystal chemistry of silver–nickel–tellurium system 279
M. SINGH and S. BHAN